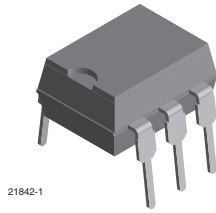
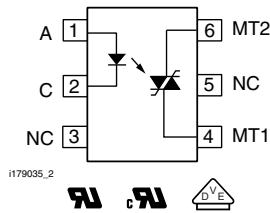


Optocoupler, Phototriac Output, High dV/dt, Low Input Current



21842-1



DESCRIPTION

The IL420 and IL4208 consists of a GaAs IRLED optically coupled to a photosensitive non-zero crossing TRIAC network. The TRIAC consists of two inverse parallel connected monolithic SCRs. These three semiconductors are assembled in a six pin dual in-line package.

High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver resulting in an LED trigger current of less than 2 mA (DC).

The use of a proprietary dV/dt clam results in a static dV/dt of greater than 10 kV/μs. This clamp circuit has a MOSFET that is enhanced when high dV/dt spikes occur between MT1 and MT2 of the TRIAC. When conducting, the FET clamps the base of the phototransistors, disabling the first stage SCR predriver.

The 600 V, 800 V blocking voltage permits control of offline voltages up to 240 V_{AC}, with a safety factor of more than two, and is sufficient for as much as 380 V_{AC}.

The IL420, IL4208 isolates low-voltage logic from 120 V_{AC}, 240 V_{AC}, and 380 V_{AC} lines to control resistive, inductive, or capacitive loads including motors, solenoids, high current thyristors or TRIAC and relays.

FEATURES

- High input sensitivity $I_{FT} = 2 \text{ mA}$
- 600 V, 800 V blocking voltage
- 300 mA on-state current
- High static dV/dt 10 kV/μs
- Very low leakage < 10 μA
- Isolation test voltage 5300 V_{RMS}
- Small 6-pin DIP package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

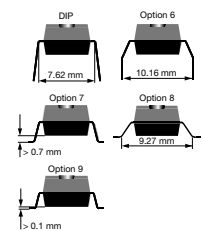
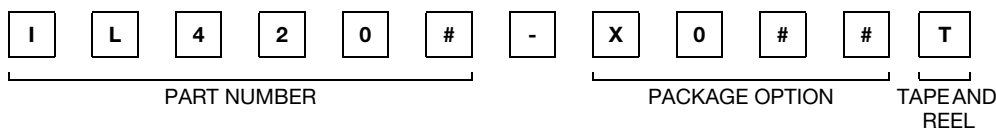
APPLICATIONS

- Solid state relays
- Industrial controls
- Office equipment
- Consumer appliances

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- DIN EN 60747-5-5 (VDE 0884) available with option 1

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	BLOCKING VOLTAGE V_{DRM} (V)	
	600	800
UL, cUL		
DIP-6	IL420	IL4208
DIP-6, 400 mil, option 6	IL420-X006	-
SMD-6, option 7	IL420-X007T ⁽¹⁾	IL4208-X007T ⁽¹⁾
SMD-6, option 8	IL420-X008T	-
SMD-6, option 9	IL420-X009T ⁽¹⁾	IL4208-X009T ⁽¹⁾
VDE, UL, cUL		
DIP-6	IL420-X001	-
DIP-6, 400 mil, option 6	IL420-X016	-
SMD-6, option 7	IL420-X017T ⁽¹⁾	-

Note

⁽¹⁾ Also available in tubes, do not put T on the end.

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾ ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Reverse voltage			V_R	6	V
Forward current			I_F	60	mA
Surge current			I_{FSM}	2.5	A
Power dissipation			P_{diss}	100	mW
Derate from 25 °C				1.33	mW/°C
OUTPUT					
Peak off-state voltage		IL420	V_{DRM}	600	V
		IL4208	V_{DRM}	800	V
RMS on-state current			I_{TM}	300	mA
Single cycle surge current			I_{TSM}	3	A
Power dissipation			P_{diss}	500	mW
Derate from 25 °C				6.6	mW/°C
COUPLER					
Isolation test voltage between emitter and detector	$t = 1\text{ s}$		V_{ISO}	5300	V_{RMS}
Pollution degree (DIN VDE 0109)				2	
Creepage distance				≥ 7	mm
Clearance distance				≥ 7	mm
Comparative tracking ⁽²⁾				≥ 175	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$		R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$		R_{IO}	$\geq 10^{11}$	Ω
Storage temperature range			T_{stg}	- 55 to + 150	°C
Ambient temperature range			T_{amb}	- 55 to + 100	°C
Soldering temperature ⁽³⁾	max. $\leq 10\text{ s}$ dip soldering $\geq 0.5\text{ mm}$ from case bottom		T_{sld}	260	°C

Notes

- ⁽¹⁾ Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽²⁾ Index per DIN IEC60112/VDE 0303 part 1, group IIIa per DIN VDE 6110.
- ⁽³⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 10 mA		V _F		1.16	1.35	V
Reverse current	V _R = 6 V		I _R		0.1	10	μA
Input capacitance	V _F = 0 V, f = 1 MHz		C _{IN}		40		pF
Thermal resistance, junction to ambient			R _{thja}		750		°C/W
OUTPUT							
Off-state voltage	I _{D(RMS)} = 70 μA	IL420	V _{D(RMS)}	424	460		V
		IL4208	V _{D(RMS)}	565			V
Repetitive peak off-state voltage	I _{DRM} = 100 μA	IL420	V _{DRM}	600			V
		IL4208	V _{DRM}	800			V
Off-state current	V _D = V _{DRM} , T _{amb} = 100 °C		I _{BD}		10	100	μA
On-state voltage	I _T = 300 mA		V _{TM}		1.7	3	V
On-current	PF = 1, V _{T(RMS)} = 1.7 V		I _{TM}			300	mA
Surge (non-repetitive), on-state current	f = 50 Hz		I _{TSM}			3	A
Holding current			I _H		65	500	μA
Latching current	V _T = 2.2 V		I _L			500	μA
LED trigger current	V _{AK} = 5 V		I _{FT}		1	2	mA
Trigger current temperature gradient			ΔI _{FT} /ΔT _j		7	14	μA/°C
Critical rate of rise off-state voltage	V _D = 0.67 V _{DRM} , T _j = 25 °C		dV/dt _{cr}	10 000			V/μs
	V _D = 0.67 V _{DRM} , T _j = 80 °C		dV/dt _{cr}	5000			V/μs
Critical rate of rise of voltage at current commutation	V _D = 230 V _{RMS} , I _D = 300 mA _{RMS} , T _J = 25 °C		dV/dt _{crq}		8		V/μs
	V _D = 230 V _{RMS} , I _D = 300 mA _{RMS} , T _J = 85 °C		dV/dt _{crq}		7		V/μs
Critical rate of rise of on-state current commutation			dI/dt _{crq}		12		A/ms
Thermal resistance, junction to ambient			R _{thja}		150		°C/W
COUPLER							
Critical rate of rise of coupled input/output voltage	I _T = 0 A, V _{RM} = V _{DM} = V _{D(RMS)}		dV/dt		5000		V/μs
Capacitance (input to output)	f = 1 MHz, V _{IO} = 0 V		C _{IO}		0.8		pF
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C		R _{IO}	≥ 10 ¹²			Ω
	V _{IO} = 500 V, T _{amb} = 100 °C		R _{IO}	≥ 10 ¹¹			Ω

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	V _{RM} = V _{DM} = V _{D(RMS)}	t _{on}		35		μs
	PF = 1, I _T = 300 mA	t _{off}		50		μs

SAFETY AND INSULATION RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}			8000			V
V_{IORM}			630			V
P_{SO}					500	mW
I_{SI}					250	mA
T_{SI}					175	$^{\circ}\text{C}$
Creepage distance	Standard DIP-8		7			mm
Clearance distance	Standard DIP-8		7			mm
Creepage distance	400 mil DIP-8		8			mm
Clearance distance	400 mil DIP-8		8			mm
Insulation thickness	For IL4208 only		0.4			mm

Note

- As per IEC60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

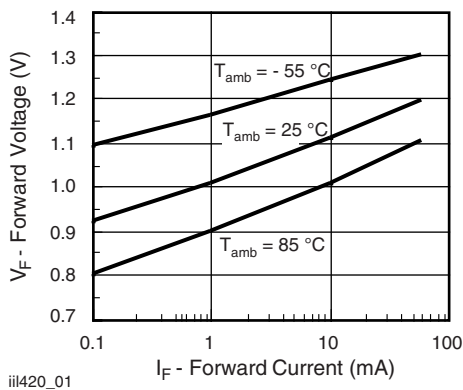


Fig. 1 - Forward Voltage vs. Forward Current

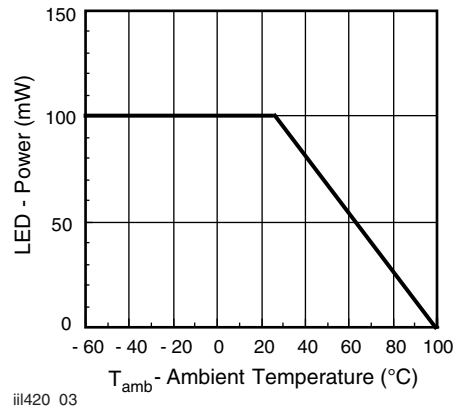


Fig. 3 - Maximum LED Power Dissipation

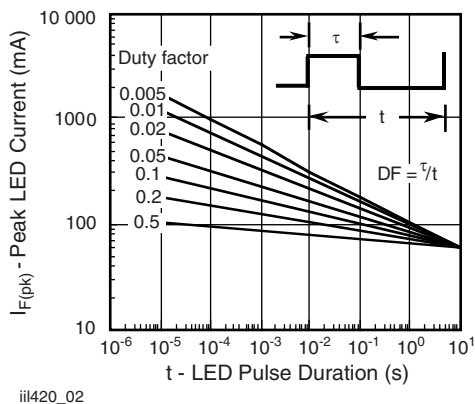


Fig. 2 - Peak LED Current vs. Duty Factor, τ

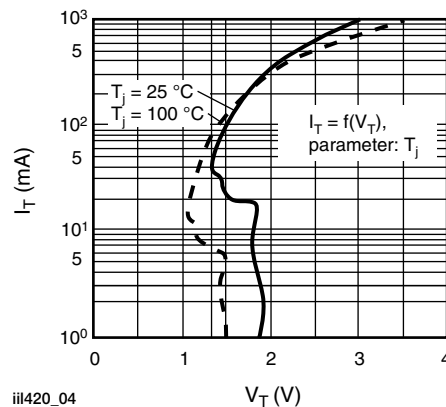


Fig. 4 - Typical Output Characteristics

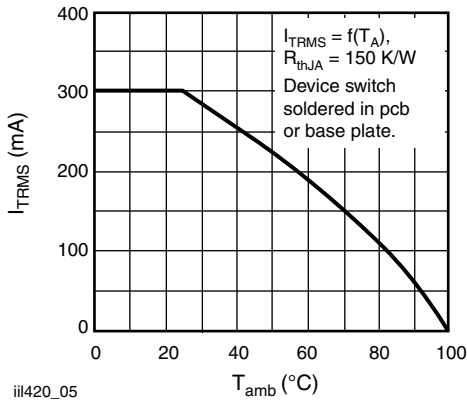


Fig. 5 - Current Reduction

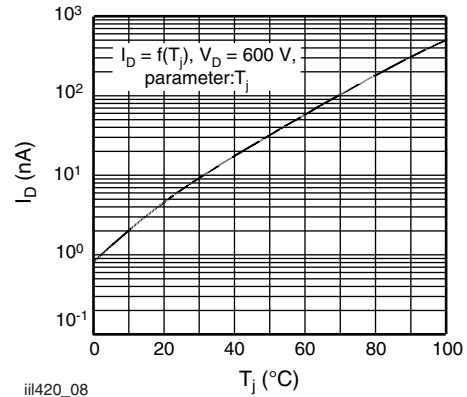


Fig. 8 - Typical Off-State Current

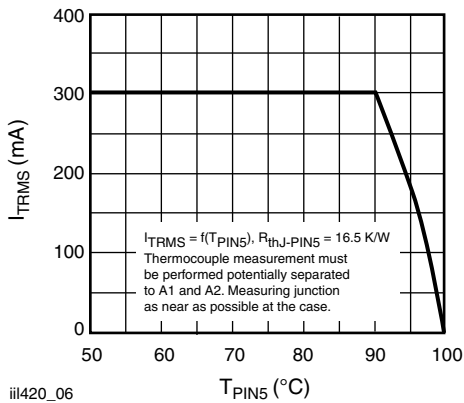


Fig. 6 - Current Reduction

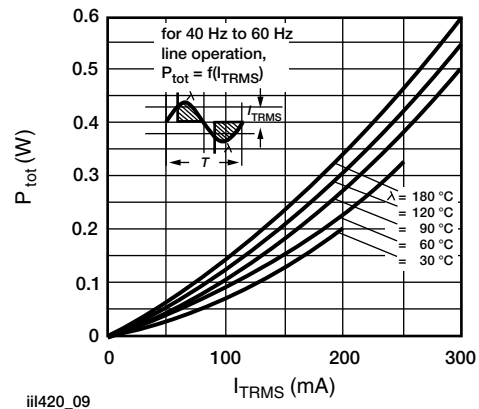


Fig. 9 - Power Dissipation

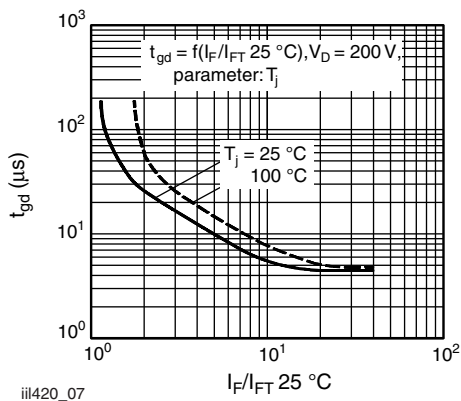


Fig. 7 - Typical Trigger Delay Time

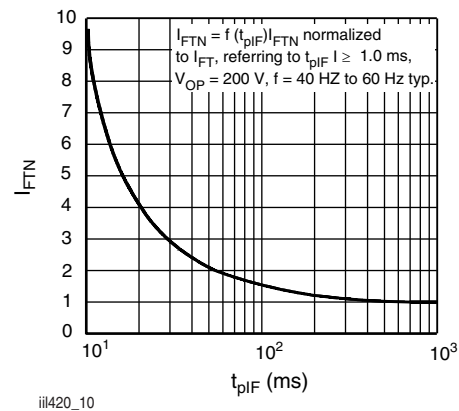


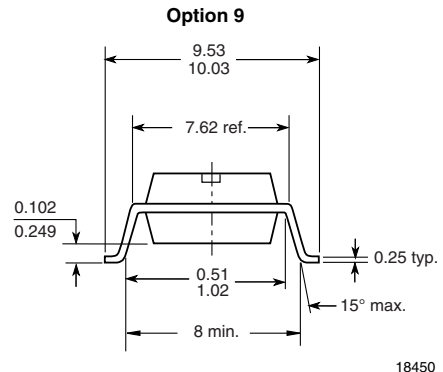
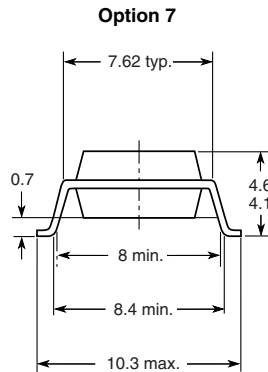
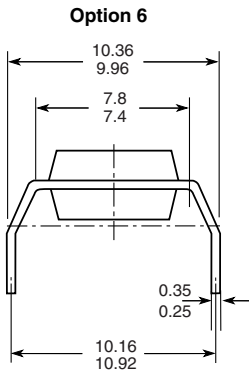
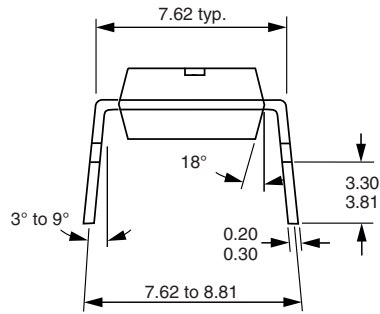
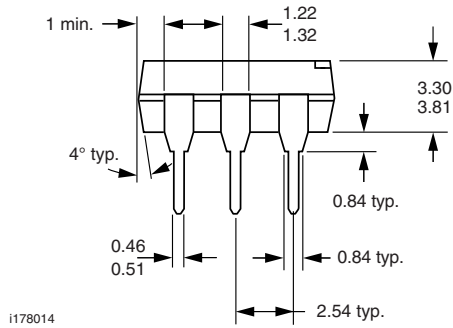
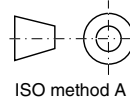
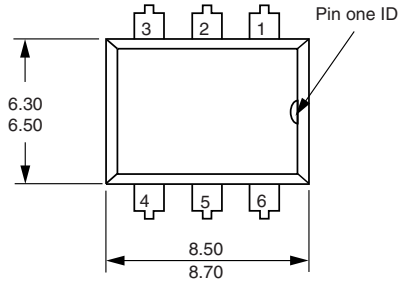
Fig. 10 - Pulse Trigger Current

IL420, IL4208



Vishay Semiconductors Optocoupler, Phototriac Output,
High dV/dt, Low Input Current

PACKAGE DIMENSIONS in (millimeters)



18450



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